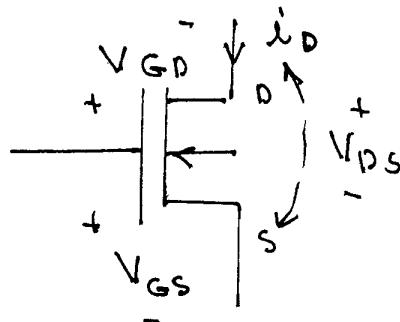


Problem 6 Problem Set 4 12.2

(3)

part a)
n-channel mosfet



n channel -

$$i_D = k [2(V_{GS} - V_{to})V_{DS} - V_{DS}^2]$$

$$V_{to} = 1 \text{ V}$$

$$k_p = 50 \mu\text{A}/\text{V}^2$$

$$L = 5 \mu\text{m}$$

$$W = 50 \mu\text{m}$$

$$\therefore k = \frac{k_p}{2} \frac{W}{L} = 50 \mu\text{A}/\text{V}^2 \times \frac{1}{2} \frac{50}{5} = 250 \mu\text{A}/\text{V}^2$$

$$\underline{| V_{GD} = V_{GS} - V_{DS} |}$$

$$\underline{\text{cut-off}} \quad V_{GS} = V_{to} = 1 \text{ V}$$

Boundary between triode and saturation

$$V_{DS} = (V_{GS} - V_{to}) = V_{GS} - 1$$

$$\therefore i_D = k [2(V_{GS} - V_{to})V_{DS} - V_{DS}^2] \text{ for } V_{DS} < V_{GS} - V_{to}$$

$$i_D = 0 \text{ for cut-off } (V_{GS} = V_{to})$$

$$i_D = k [(V_{GS} - V_{to})^2] \text{ in saturation region}$$